

# Contents

<b>Abstract</b>	iii
<b>Kurzfassung</b>	vii
<b>Introduction</b>	1
<b>1 Theoretical foundation for high power DFB lasers</b>	7
1.1 Power conversion efficiency . . . . .	8
1.1.1 Power conversion efficiency in DFB and FP lasers . . . . .	8
1.1.2 Optical output power . . . . .	9
1.1.3 Electrical power consumption . . . . .	13
1.1.4 How to achieve a high peak power conversion efficiency	14
1.1.5 Continuous wave power and efficiency characteristics .	22
1.2 Distributed feedback in semiconductor lasers . . . . .	28
1.2.1 The principle of distributed feedback . . . . .	28
1.2.2 Coupled mode theory and coupling coefficients for second-order DFB gratings . . . . .	35
1.2.3 Threshold condition for DFB lasers . . . . .	43
1.2.4 Approximations and numerical solutions for DFB-BA lasers . . . . .	44
1.2.5 Power and efficiency characteristics of DFB-BA lasers	58
1.2.6 Important aspects for the design of efficient high power DFB-BA lasers . . . . .	63
<b>2 DFB-BA laser review</b>	67
<b>3 Experimental and theoretical results from iteration I</b>	75
3.1 Design of a low loss laser waveguide . . . . .	76
3.2 Characterization of FP-BA reference lasers . . . . .	84
3.2.1 Facet coating for FP-BA reference lasers . . . . .	84
3.2.2 P-U-I characteristics of FP-BA lasers . . . . .	85

3.2.3	Spectral properties of FP-BA lasers . . . . .	87
3.2.4	Thermal properties of FP-BA lasers . . . . .	89
3.2.5	Spatial emission properties of FP-BA lasers . . . . .	93
3.3	Development of the DFB grating . . . . .	96
3.3.1	Properties of the DFB grating . . . . .	96
3.3.2	Manufacturing of the DFB grating . . . . .	105
3.3.3	Coupling coefficient of the DFB grating . . . . .	113
3.4	Characterization of DFB-BA lasers . . . . .	121
3.4.1	Material parameters of DFB-BA wafers . . . . .	121
3.4.2	Facet coating for DFB-BA lasers . . . . .	124
3.4.3	Overview of DFB wafers . . . . .	124
3.4.4	Power-voltage-current characteristics of DFB-BA lasers . . . . .	127
3.4.5	Comparison of the power-voltage-current characteristics with FP-BA reference lasers . . . . .	132
3.4.6	Spectral properties of DFB-BA lasers . . . . .	136
3.4.7	Thermal properties of DFB-BA lasers . . . . .	145
3.4.8	Spatial emission properties of DFB-BA lasers . . . . .	151
3.4.9	Properties of higher-order vertical waveguide modes . . . . .	161
3.4.10	Experimental determination of the coupling coefficient . . . . .	168
3.4.11	Determination of the DFB locking range . . . . .	175
3.4.12	Spectrally resolved lateral near fields and far fields . . . . .	178
3.5	Comparison of experimental and theoretical results for threshold current and slope efficiency . . . . .	191
3.6	Conclusions from iteration I . . . . .	199
<b>4</b>	<b>Experimental and theoretical results from iteration II</b>	<b>207</b>
4.1	A concept for the further enhancement of the electro-optical properties of DFB-BA lasers . . . . .	208
4.2	Development of a further optimized DFB grating . . . . .	209
4.2.1	Changes of the properties of the DFB grating . . . . .	209
4.2.2	Manufacturing of the DFB grating . . . . .	213
4.2.3	Coupling coefficient of the DFB grating . . . . .	220
4.3	Characterization of DFB-BA lasers . . . . .	226
4.3.1	Overview of DFB wafers . . . . .	226
4.3.2	Facet coating for DFB-BA lasers . . . . .	227
4.3.3	Material parameters of DFB-BA wafers . . . . .	229
4.3.4	Power-voltage-current characteristics of DFB-BA lasers . . . . .	230

4.3.5	Comparison of the power-voltage-current characteristics with FP-BA reference lasers and DFB-BA lasers from iteration I . . . . .	233
4.3.6	Spectral properties of DFB-BA lasers . . . . .	241
4.3.7	Determination of the DFB locking range . . . . .	256
4.3.8	Experimental determination of the coupling coefficient	258
4.3.9	Analysis of the reliability of DFB-BA lasers . . . . .	264
4.4	Comparison of experimental and theoretical results for threshold current and slope efficiency . . . . .	273
<b>5</b>	<b>Evaluation of the electro-optical properties: Comparison to other publications</b>	<b>279</b>
<b>6</b>	<b>Summary</b>	<b>301</b>
	<b>Appendix</b>	<b>313</b>
<b>A</b>	<b>Fabrication and mounting</b>	<b>313</b>
A.1	Wafer fabrication . . . . .	313
A.2	Wafer processing . . . . .	313
A.3	Facet coating . . . . .	314
A.4	Mounting of single emitters . . . . .	315
<b>B</b>	<b>Measurement methods</b>	<b>317</b>
B.1	Measurements under CW conditions . . . . .	317
B.1.1	Measurement of power-voltage-current characteristics .	317
B.1.2	Measurement of optical spectra . . . . .	318
B.1.3	Measurement of vertical and lateral near fields and far fields . . . . .	319
B.1.4	Spectrum measurements with fiber coupling . . . . .	319
B.2	Measurements under short pulse conditions . . . . .	320
B.2.1	Power-voltage-current characteristics and spectra of mounted single emitters . . . . .	320
B.2.2	Power-voltage-current characteristics and spectra of unmounted single emitters on laser bars . . . . .	321
B.3	Measurement of spectrally resolved lateral near fields and far fields . . . . .	322



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<b>Bibliography</b>	<b>325</b>
<b>Publications, talks and patent</b>	<b>343</b>
<b>Abbreviations and Symbols</b>	<b>347</b>